

## Hyperfast Soft Recovery Diode, 60 A FRED Pt<sup>®</sup> Gen 4



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	60 A				
$V_{R}$	600 V				
V <sub>F</sub> at I <sub>F</sub>	1.48 V				
t <sub>rr</sub> typ.	see Recovery table				
T <sub>J</sub> max.	175 °C				
Package	TO-247AD 2L				
Circuit configuration	Single				

#### **FEATURES**

- Gen 4 FRED Pt® technology
- Low I<sub>RRM</sub> and reverse recovery charge
- · Very low forward voltage drop
- Polyimide passivated chip for high reliability standard



- 175 °C operating junction temperature
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

#### **DESCRIPTION**

Gen 4 Fred technology, state of the art, ultralow  $V_F$ , soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Cathode to anode voltage	$V_R$		600	V		
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 106 °C	60	۸		
Single pulse forward current	I <sub>FSM</sub>	$T_C$ = 25 °C, $t_p$ = 8.3 ms, half sine wave	425	А		
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL TEST CONDITIONS			TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	600	-	-		
Forward voltage		I <sub>F</sub> = 50 A	-	1.68	-	V	
	V <sub>F</sub>	I <sub>F</sub> = 60 A	-	1.75	2.0		
		I <sub>F</sub> = 50 A, T <sub>J</sub> = 125 °C	-	1.44	-		
		I <sub>F</sub> = 60 A, T <sub>J</sub> = 125 °C	-	1.55	-		
		I <sub>F</sub> = 50 A, T <sub>J</sub> = 150 °C	-	1.39	-		
		I <sub>F</sub> = 60 A, T <sub>J</sub> = 150 °C	-	1.48	1.65		
Deviares legicare ourrent		V <sub>R</sub> = V <sub>R</sub> rated	-	-	50		
Reverse leakage current	I <sub>R</sub>	T <sub>J</sub> = 125 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	-	500	μA	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	30	-	pF	



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST C	MIN.	TYP.	MAX.	UNITS		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 60 A dI <sub>F</sub> /dt = 1000 A/μs V <sub>R</sub> = 400 V	-	68	-	ns	
Reverse recovery time		T <sub>J</sub> = 125 °C		-	92	-		
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	20	-	A	
		T <sub>J</sub> = 125 °C		-	40	-		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	945	-	nC	
		T <sub>J</sub> = 125 °C		-	2500	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	0.6			
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	40	°C/W		
Thermal resistance, case to heat sink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.25	-			
Weight			=.	6.0	-	g		
Weight			-	0.21	-	oz.		
Mounting torque			6.0 (5)	-	12 (20)	kgf · cm (lbf · in)		
Marking device		Case style TO-247AD 2L	E4PH6006L					

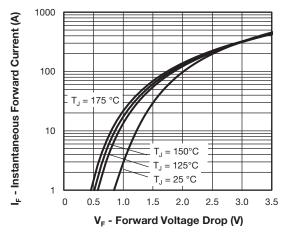


Fig. 1 - Typical Forward Voltage Drop Characteristics

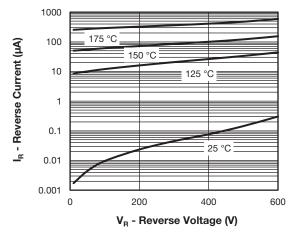


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

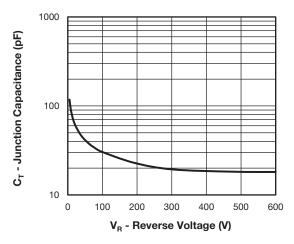


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

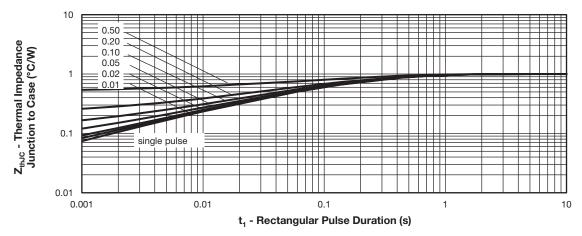


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

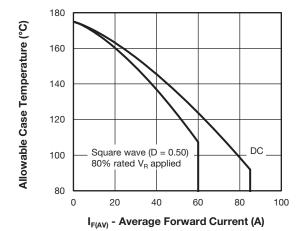


Fig. 5 - Max. Allowable Case Temperature vs. Average Forward Current

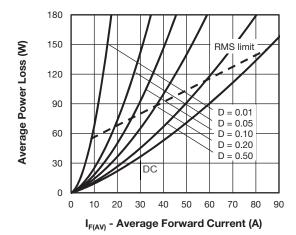


Fig. 6 - Forward Power Loss Characteristics

#### Note

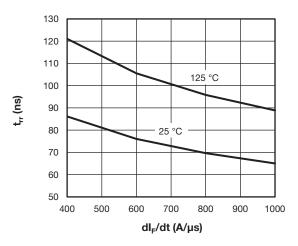
 $\begin{array}{l} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at } (I_{F(AV)}/D) \ \text{(see Fig.5)} \\ P_{dREV} = \text{inverse power loss} = V_{R1} \times I_R \ \text{(1 - D); } I_R \ \text{at } V_R = \text{rated } V_R \\ \end{array}$ 

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# Vishay Semiconductors



3000 2500 125 °C 2000 Q<sub>rr</sub> (nC) 1500 1000 25 °C 500 0 500 600 700 800 1000 400 900 dI<sub>F</sub>/dt (A/μs)

Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

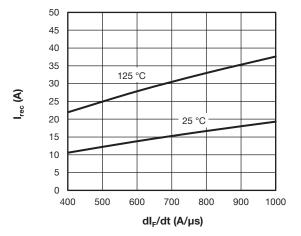
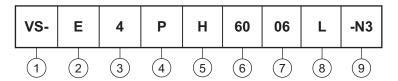


Fig. 9 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt



### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Circuit configuration:

E = single diode 2 pins

3 - FRED Gen 4

- P = TO-247 package

5 - Process type:

H = hyperfast recovery

6 - Current rating (60 = 60 A)

7 - Voltage rating (06 = 600 V)

8 - L = long lead

9 - Environmental digit:

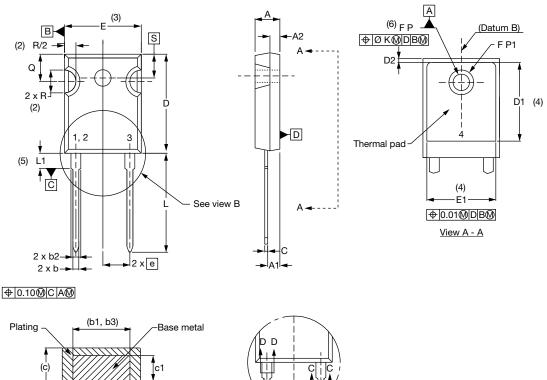
-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-E4PH6006L-N3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95536</u>					
Part marking information	www.vishay.com/doc?95648				

### **TO-247AD 2L**

### **DIMENSIONS** in millimeters and inches



D D C C
<u>View B</u>

CVMPOL	SYMBOL MILLIMETERS		MILLIMETERS INCHES		NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

SYMBOL	MILLIMETERS		INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.2	0.254		0.010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	

#### **Notes**

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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